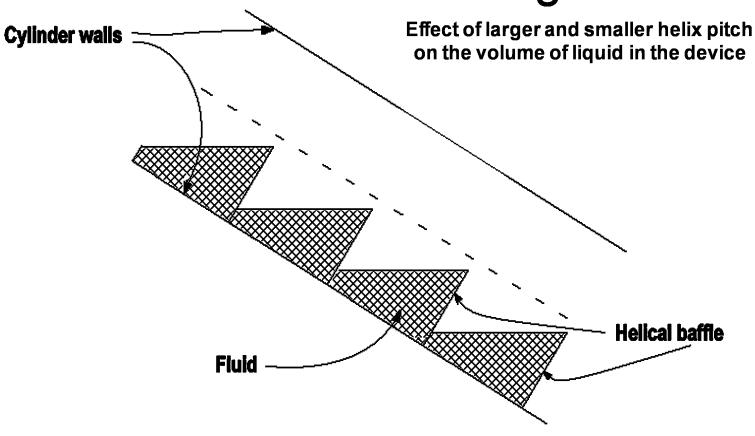
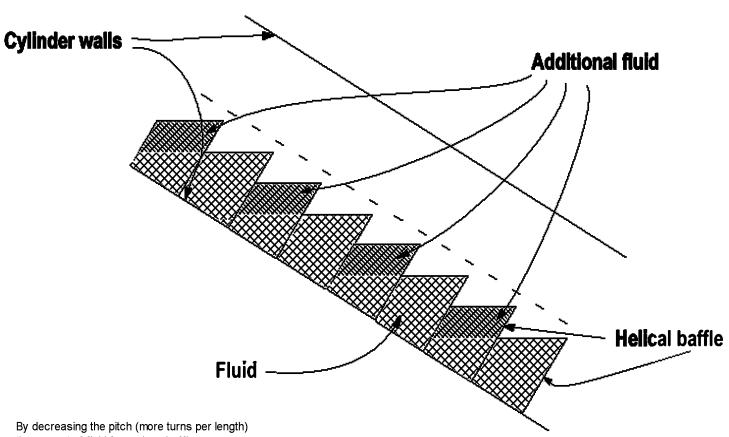
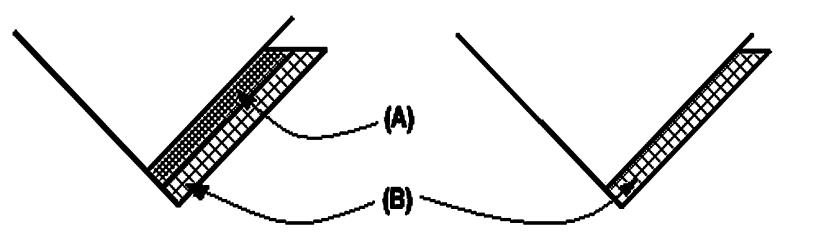
Figure 1





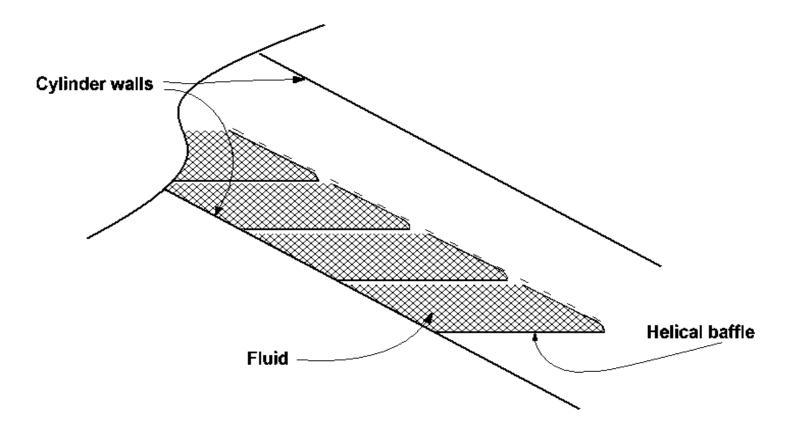
the amount of fluid for a given baffle crosss section is increased. The addition volume in the low er drawing with a smaller pitch is shown with a different hatch pattern.



The average potential energy of water spilled from a higher pitch helix is larger than a low er pitch. Proof is provided by showing that the additional fluid cross section (A) in a higher helix pitch will have a higher center of gravity than the common cross sections (B)

Figure 2

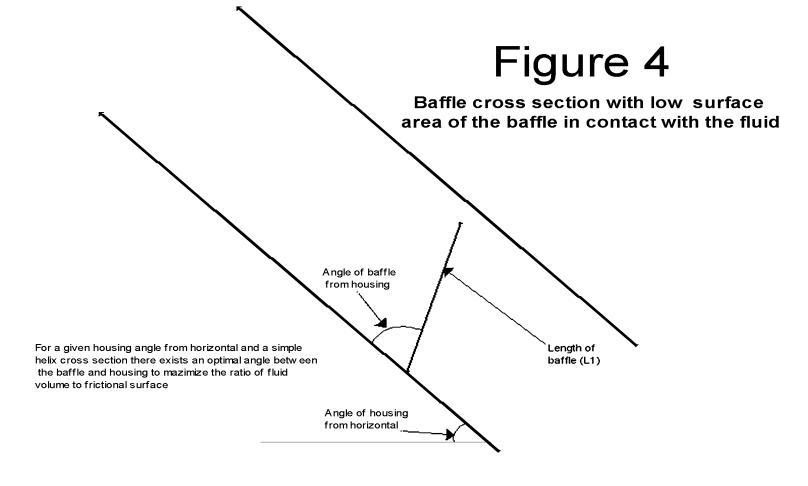
Effect of larger and smaller helix pitch on the spill effect at the exit of the device



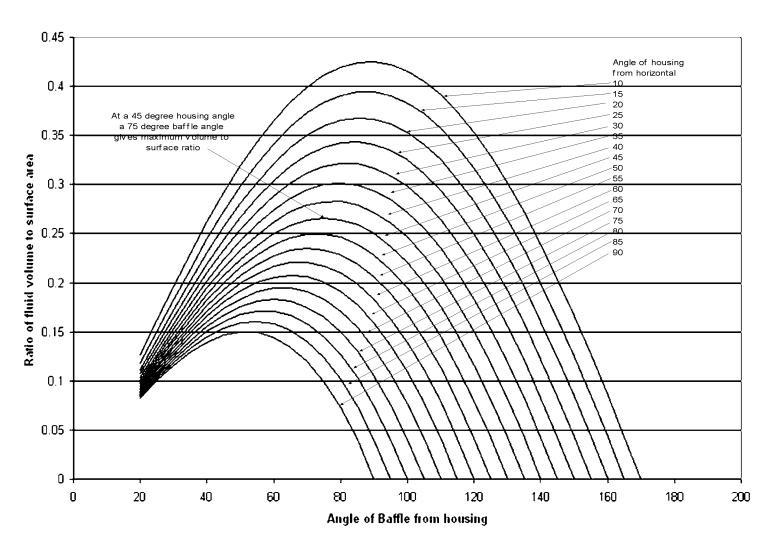
By varing the cross sectional design of the baffle, the amount of fluid contained housing can approach 1/2 the volume of the housing.

Figure 3

baffle cross section with a high volume of water captured in a helix turn



Effect of housing and baffle angles on volume to surface rationgles



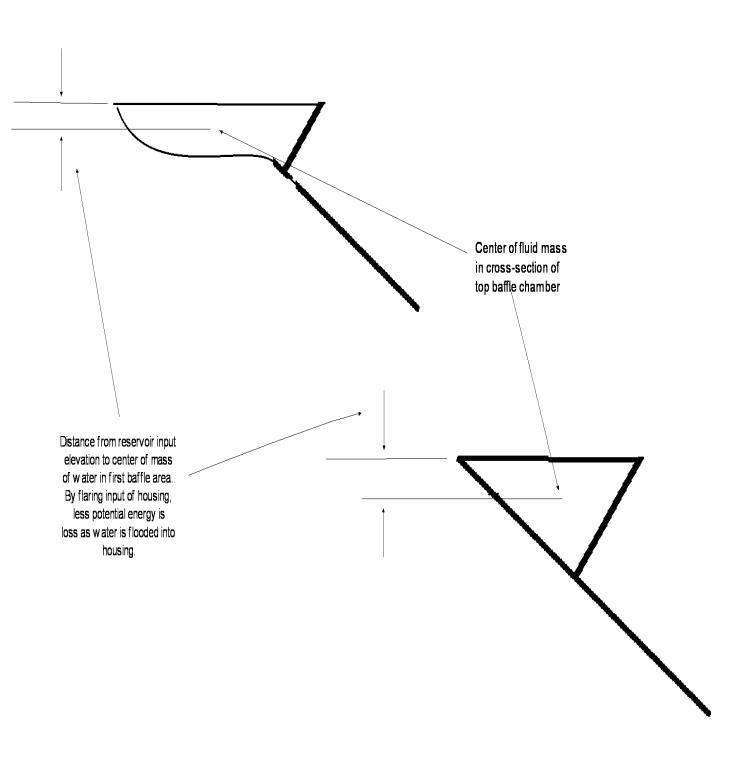
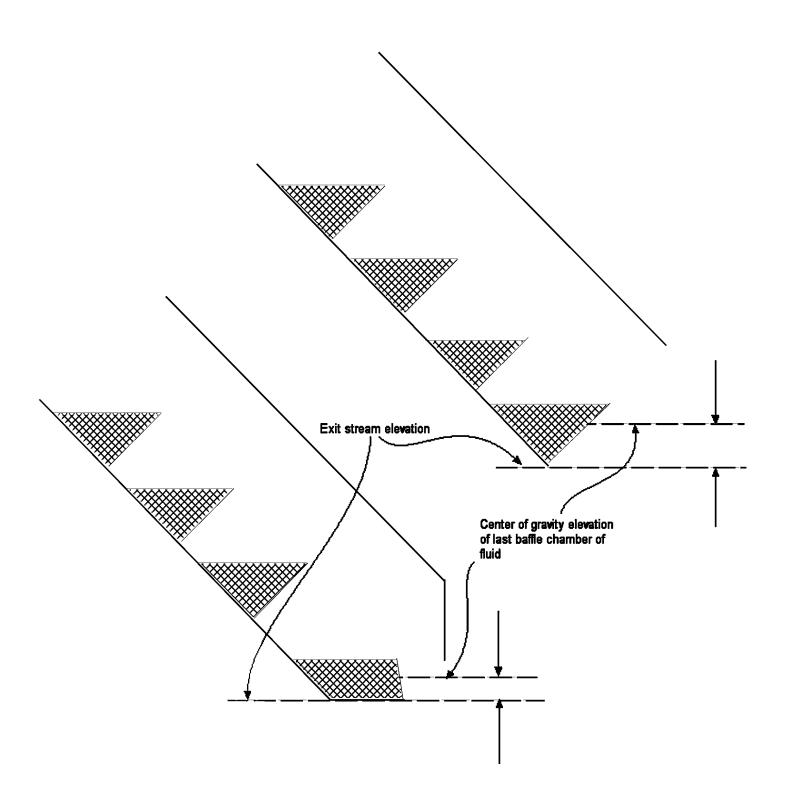


Figure 5

Effect of larger radius and helix pitch at the entrance of the device

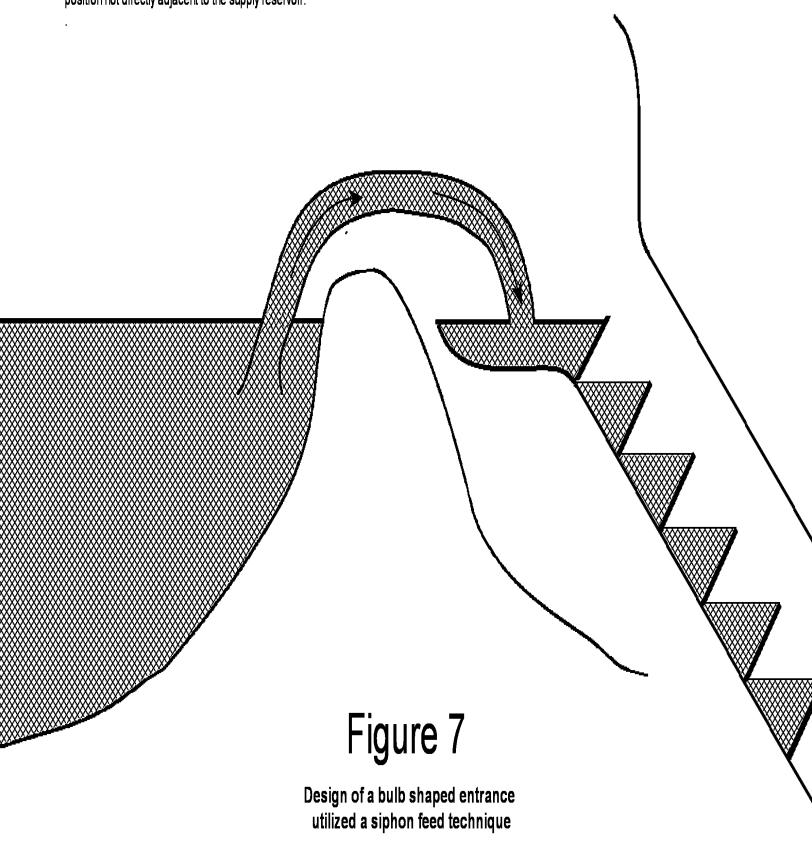


By flattening the exit baffle cavity, the center of gravity of the exiting fluid is lowered prior to dumping and thereby reduces the uncaptured potential energy when the fluid is "spilled" to the exit stream

Figure 6

Effect of larger radius and helix pitch at the exit of the device

Siphoning mechanism at entrance to device would allow for flexibility in height of supply reservoir, simplification of fluid entry configuration and the ability for the device to be located in a position not directly adjacent to the supply reservoir.



Sections of the housing and baffle can be added or removed to change the length of the device and thereby adjust the entrance elevation as needed based on the level of the supply reservour. Figure 8

Change in input elevation via shortening or lengthening of the device

Changes in the elevation of the suppy reservour can be adjusted for by changing the angle of the housing and adjusting the dam spill level as depicted by the arrows below.

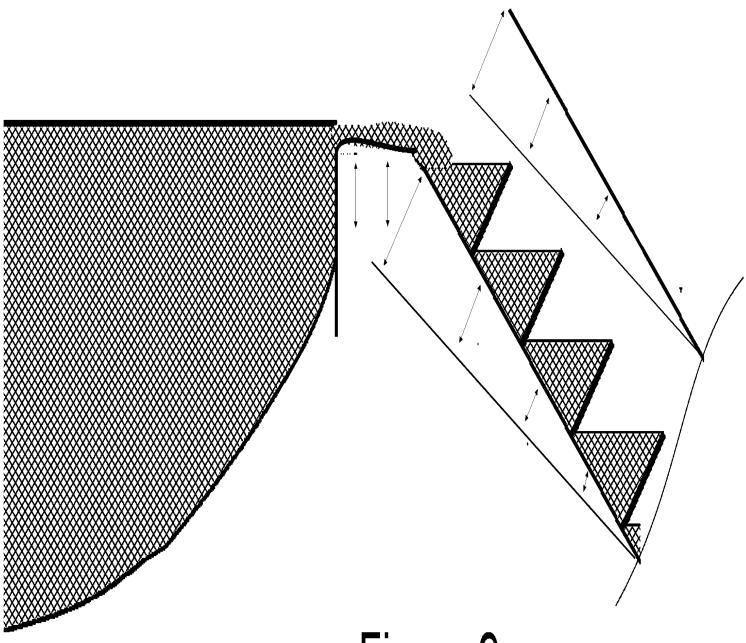


Figure 9

Change in input elevation via changing the angle of the device

